

# ESH3B, ESH3C & ESH3D

## Vishay General Semiconductor

## **Surface Mount Ultrafast Plastic Rectifier**



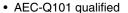
DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	3.0 A				
V <sub>RRM</sub>	100 V, 150 V, 200 V				
t <sub>rr</sub>	25 ns				
V <sub>F</sub>	0.90 V				
T <sub>J</sub> max.	175 °C				

#### **FEATURES**

- · Glass passivated chip junction
- · Ideal for automated placement
- Ultrafast recovery times for high efficiency
- · Low forward voltage, low power loss
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum AUTOMOTIVE GRADE peak of 260 °C

  Available



- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Find out more about Vishay's Automotive Grade Product requirements at: <a href="https://www.vishay.com/applications">www.vishay.com/applications</a>

#### TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer and automotive.

#### **MECHANICAL DATA**

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002

and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test **Polarity:** Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	$V_{RMM}$	100	150	200	V	
Maximum RMS voltage	V <sub>RMS</sub>	70	105	140	V	
Maximum DC blocking voltage	$V_{DC}$	100	150	200	V	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	3.0		Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	125			А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175			°C	

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ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage (1)	I <sub>F</sub> = 3 A		V <sub>F</sub>	0.90	V	
Maximum DC reverse current at rated DC blocking voltage		T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	5.0 150	μΑ	
Maximum reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	25	ns	
Typical reverse recovery time	$I_F = 3 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C	t <sub>rr</sub>	40 55	ns	
Typical stored charge	$I_F = 3 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C	Q <sub>rr</sub>	25 60	nC	
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT
Typical thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJL}$	50 15		°C/W	

#### Note

<sup>(1)</sup> Units mounted on P.C.B. with 12.0 x 12.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH3D-E3/57T	0.211	57T	850	7" diameter plastic tape and reel		
ESH3D-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel		
ESH3DHE3/57T (1)	0.211	57T	850	7" diameter plastic tape and reel		
ESH3DHE3/9AT (1)	0.211	9AT	3500	13" diameter plastic tape and reel		

#### Note

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

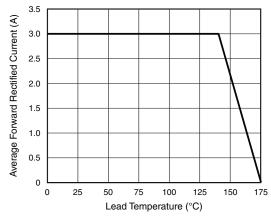


Fig. 1 - Maximum Forward Current Derating Curve

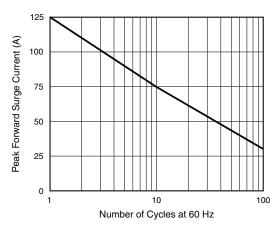


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

<sup>(1)</sup> Automotive grade



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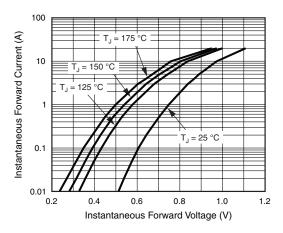


Fig. 3 - Typical Instantaneous Forward Characteristics

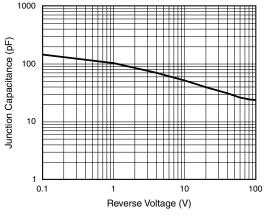


Fig. 5 - Typical Junction Capacitance

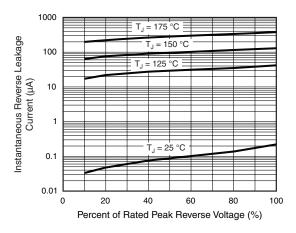


Fig. 4 - Typical Reverse Leakage Characteristics

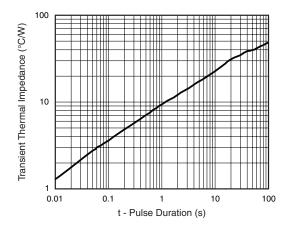
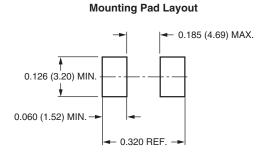


Fig. 6 - Typical Transient Thermal Impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### DO-214AB (SMC) Cathode Band 0.246 (6.22) 0.126 (3.20) 0.220 (5.59) 0.114 (2.90) 0.280 (7.11) 0.260 (6.60) 0.012 (0.305) 0.006 (0.152) 0.103 (2.62) 0.079 (2.06) 0.008 (0.2) 0.060 (1.52) 0.030 (0.76) 0 (0) 0.320 (8.13) 0.305 (7.75)







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